

## Supplementary information

### **Reliable interfaces for EGaN multi-layer stretchable circuits and microelectronics**

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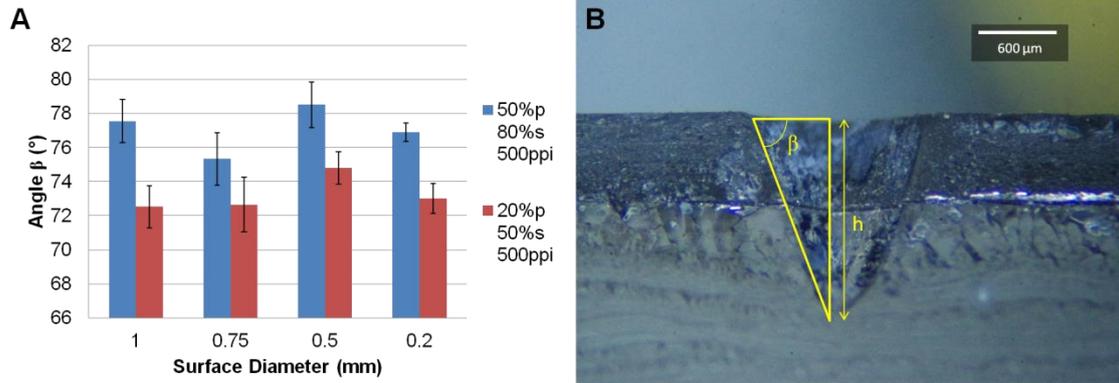
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### **Supporting Material:**

Ablation Angle  
Estimation of Maximum Depth  
Cross-sectional view of ablation  
Dimensions of Tensile Specimens  
Additional Tensile Tests  
Cyclic loading test setup  
Video: Demos

## Ablation Angle of VIAs



**Figure S1 – A.** Internal angle of ablation ( $\beta$ ) in function of the surface diameter of ablation for two different sets of parameters of the laser printer (blue: 50%p 80%s 500ppi; red: 25%p 50%s 500ppi). The angle is approximately constant for each set of parameters, regardless of the surface diameter of the VIA. Lower ablation angles correspond to the ablation with a lower energy beam. **B.** Schematic drawing, on a microscopic cross-section photograph, of the triangle model to estimate, using simple trigonometry, the maximum depth ( $h$ ) for a certain ablation angle.

## Estimation of Maximum Depth of VIAs

$\beta$ : Angle at the base of the cone

$h$ : Depth of the Via

$d$ : Surface diameter

$\sigma$ : Standard deviation

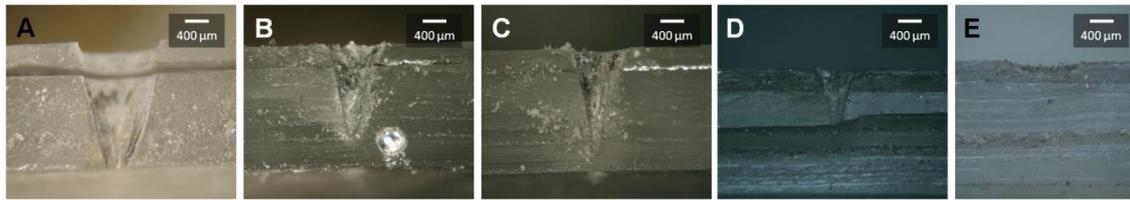
$$h = \frac{d}{2} \tan \beta \quad (1)$$

$$\sigma_h = \sigma_\beta \frac{d}{2} \frac{1}{\cos^2 \beta} \quad (2)$$

Equation 1: Estimated depth  $h$  of ablation given the angle  $\beta$ .

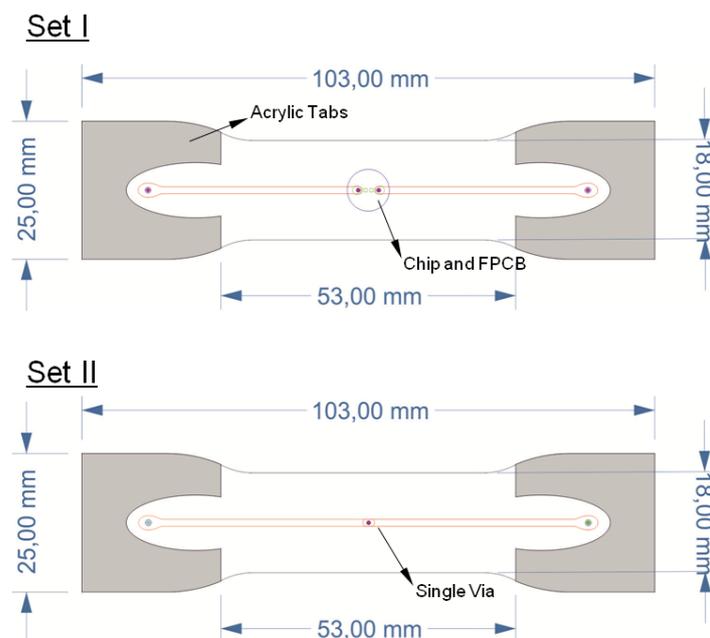
Equation 2: Standard deviation of the calculated  $h$  based on the standard deviation of averaged  $\beta$  experimental measurements.

## Cross-sectional view of ablation



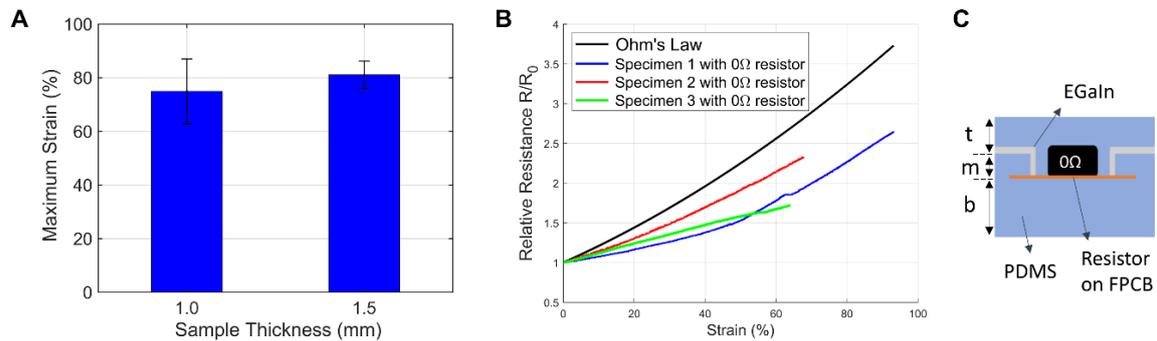
**Figure S2** – Cross-section microscope view of the ablation of PDMS and EGaln layer after 12 passes on the laser printer with 50%p 80%*s* 500ppi laser settings and for different surface diameters: **A.** 1 mm **B.** 0.75 mm **C.** 0.5 mm **D.** 0.2 mm. **E.** No ablation occurred with 5%p 15%*s* 500ppi and 1 mm of diameter.

## Dimension of tensile specimens



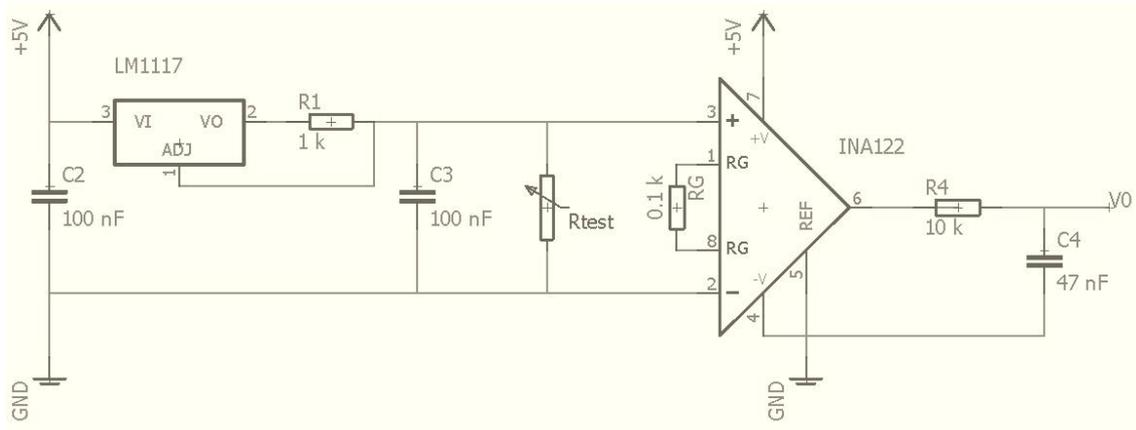
**Figure S3** – Dimensions of the custom dog-bone shaped samples prepared for the electromechanical tests. As described in the paper, each sample has a conductive EGaln trace between both ends of the sample, where an additional FPCB connector was attached (not shown in the picture). At the center of each sample: Set I has a 0  $\Omega$  resistor chip (YAGEO 0.063W, 1/16W Chip Resistor, 0402 packaging) soldered to a circular FPCB; Set II has a EGaln VIA connecting the traces running from both ends of the sample; Set III (not shown in the picture), as a reference, has a single EGaln trace between both ends of the sample. Thickness of the samples: 1.50 mm.

## Additional Tensile Tests



**Figure S4 – A.** Electromechanical tensile tests were performed on samples 1.0 mm and 1.5 mm thick. The results for maximum strain at break were  $74.9 \pm 12.1$  % and  $81.1 \pm 5.1$  %, respectively. **B.** Relative resistance of 1.0 mm thick samples with an interfaced  $0\Omega$  resistor chip on a flexible island. **C.** Side-view schematics of samples.  $b$ ,  $m$ , and  $t$  refer to the respective PDMS thicknesses. For 1.5 mm thick samples:  $b=750\mu\text{m}$ ,  $m=250\mu\text{m}$ ,  $t=500\mu\text{m}$ . For 1.0 mm thick samples:  $b=500\mu\text{m}$ ,  $m=150\mu\text{m}$ ,  $t=350\mu\text{m}$ .

## Cyclic loading electronic test setup



**Figure S4 –** Analog circuit to measure the variable resistance ( $R_{\text{test}}$ ) of the sample and condition the signal input to the ADC of the microcontroller. Supplied with 5 V, a stage of constant current supply is composed by a LM1117 voltage regulator, as shown, and a resistor to fix the output current, which flows through the sample ( $R_{\text{test}}$ ). Here, the voltage drop across the sample is measured with a INA122 instrumentation amplifier (single-supply, low input bias current, rail-to-rail output). High frequency noise is filtered with a low-pass filter ( $R4$ ,  $C4$ ) from the voltage output.